Subgroup meeting-10/12 Introduction of thermal transport

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Thermal conductivity
Micro-scale thermal conduction
Mean free path

Micro-scale

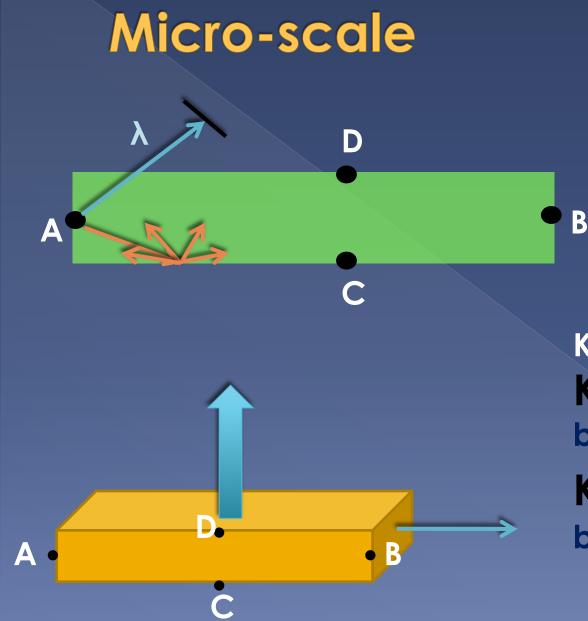
In what scale can we lower the conductivity of phonons effectively?

Depend on mean free pathDifferent geometric structures

Thermal conductivity

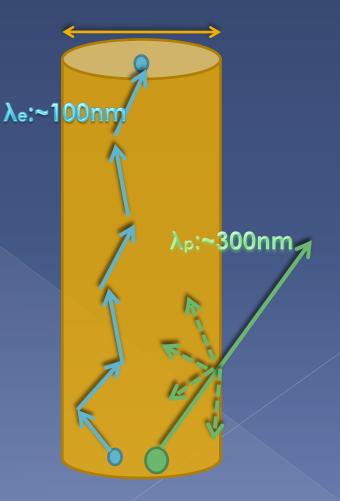
• Heat flux $j_u = -K \frac{\partial T}{\partial x}$

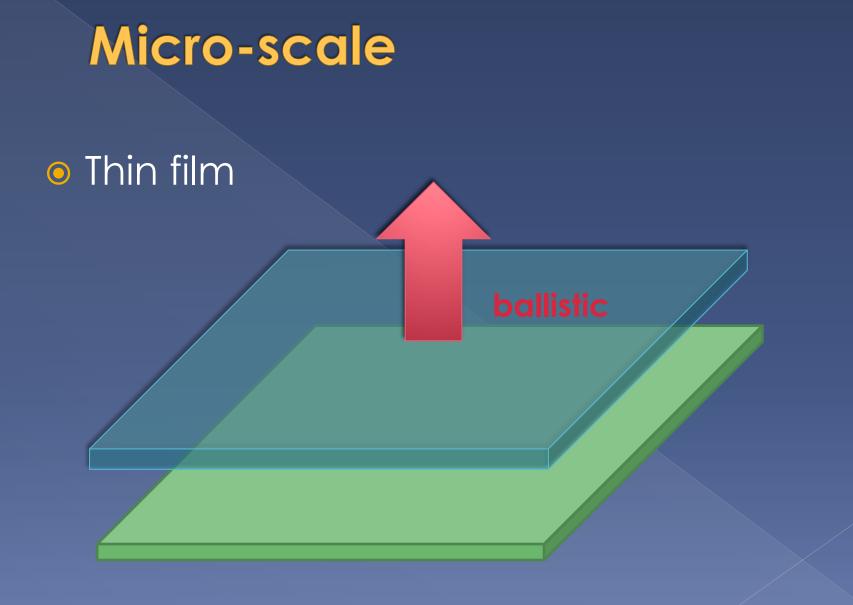
Depends on temp gradient
Not single direction
Collision



K: thermal conductivity KA-B: ~ 0 boundary scattering KC-D: ~ [∞] ballistic Micro-scale
Nanowire
Boundary scattering

- Diameter ~200nm
- Electron mean free path
 ~100nm
- Phonon mean free path
 ~from 5nm to 10mm





Micro-scale

Obvious Boundary scattering:

Phonon energy scattered by boundary(local potential difference) before the original theoretical mean free path.

Micro-scale

General consideration
 Nano scale (0.1~1µm)

Large scale
 Action Action Scale
 Action Action Scale
 Action Action Scale
 Action Action Action Scale
 Action Action

Small scale
 →different scattering mechanism

Mean free path

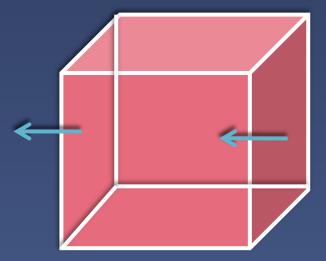
• Phonon Thermal conductivity **K** $K = \frac{1}{3} Cvl$

C: total phonon heat capacity
 v : average phonon velocity
 I : average phonon mean free path

Mean free path

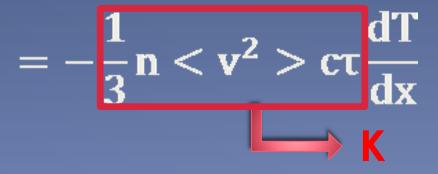
 $\Delta T = \frac{dT}{dx}I = \frac{dT}{dx}v_{x}\tau$

 $j_{u} = - \langle v_{x} \rangle \operatorname{nc}\Delta T$ $j_{u} = -n \langle v_{x}^{2} \rangle \operatorname{ct}\frac{dT}{dx}$



Flux(#) in x-direction $\frac{1}{2} < |Vx| > n$

 $\Delta E = c\Delta T$

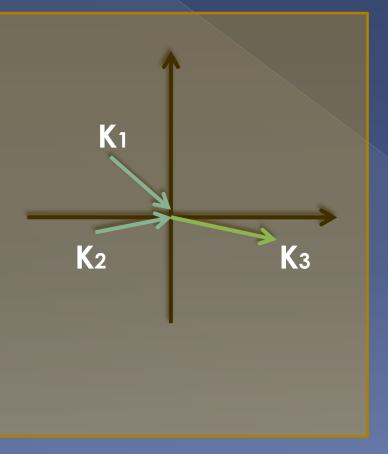


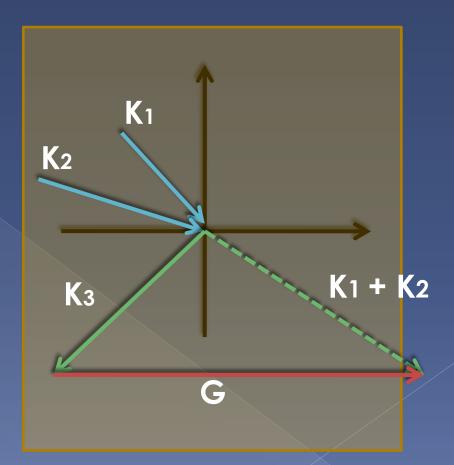
Mean free path

$K = \frac{1}{3} Cvl$

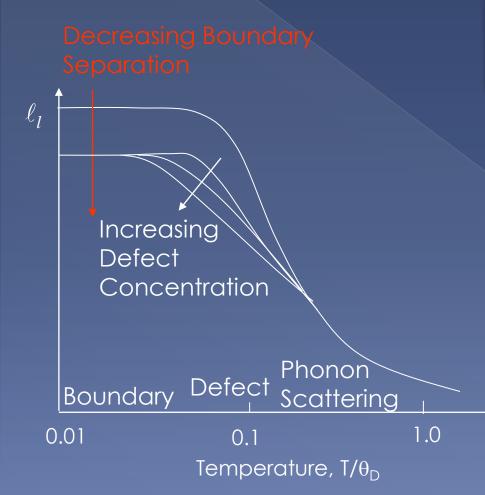
Relation between K and I
 How do we describe I (average mean free path)?

Umklapp scattering process

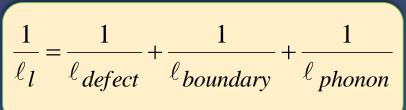




Phonon Thermal Conductivity



Matthiessen Rule:



Phonon Scattering Mechanisms

- Boundary Scattering
- Defect & Dislocation Scattering
- Phonon-Phonon Scattering

Thank you for your attention